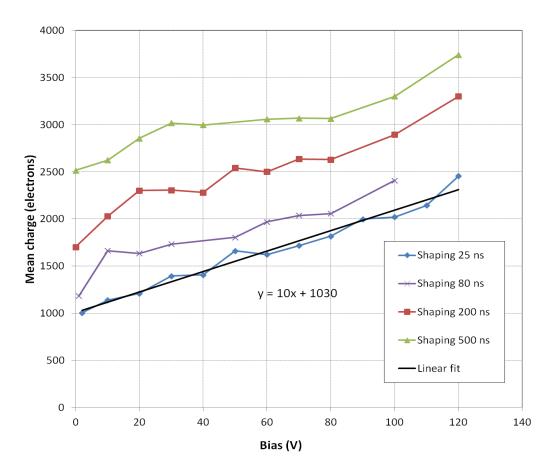
Charge collection measurements with large passive array on CHESS-1 chip irradiated with neutrons

I. Mandić et al., Jožef Stefan Institute, Ljubljana, Slovenia

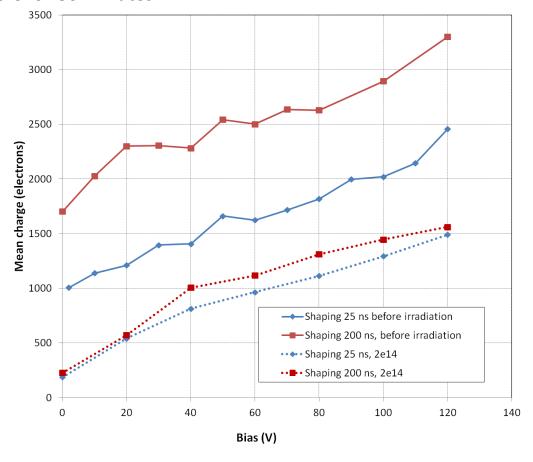
- experimental setup and first results shown at the last meeting https://indico.desy.de/getFile.py/access?contribId=4&sessionId=0&resId=0&materialId=slides&confId=11374
- → measure collected charge with large passive array with Sr90
- → measure with charge sensitive amplifier and custom made shaper with selectable shaping times
- in this presentation:
 - measurements before irradiation up to 120 V
 - first results with device irradiated in reactor with neutrons to Φ_{eq} = 2e14 n/cm²

Before irradiation



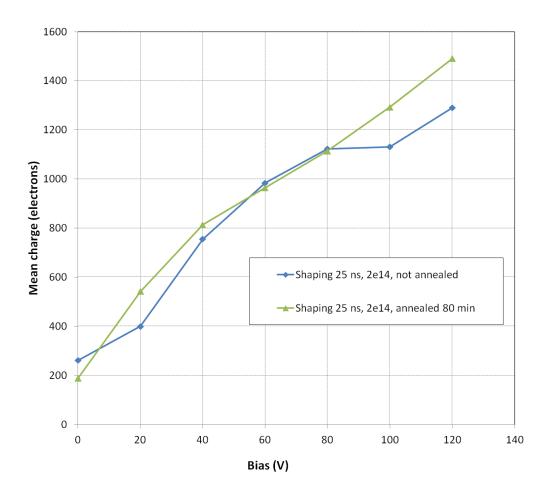
- measurements extended up to bias of 120 V
- relation at 25 ns: Mean charge = 1030 el + 10 el/V

- sample irradiated in TRIGA reactor in Ljubljana to equivalent fluence Φ_{eq} = 2e14 n/cm²
- annealed at 60 C for 80 minutes

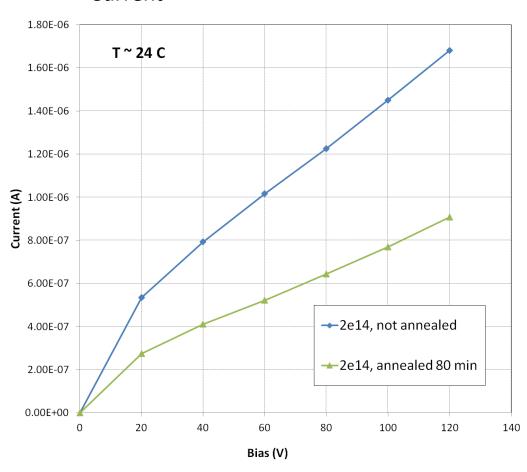


- →at 25 ns shaping about 35 % less charge measured after irradiation at high voltage
- → small dependence on shaping time after irradiation → small contribution from diffusion

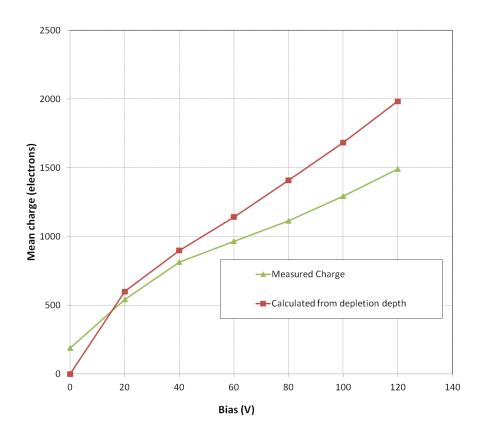
• small effect of annealing on measured charge



Current



- from current after annealing depleted depth can be estimated: $w = I/\alpha \Phi S$ $\alpha = 4e-17$ A/cm, S = 2 mm², correction factor 0.7 because current measured at T = 24 C
- → charge can be estimated from depleted depth assuming mean charge 100 el/µm



Summary:

Before irradiation

- at 25 ns shaping: Mean charge = 1030 el + 10 el/V
- collected charge increases with longer shaping times

After irradiation with neutrons Φ_{eq} = 2e14 n/cm²

- at 25 ns shaping about 35% less charge measured at high bias voltage
- small dependence on shaping time → small contribution from diffusion
- measured charge agrees with estimation from depleted depth calculated from leakage current